Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	43	spring with curve and stack and dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:26
L2	40	spring with curve and stack and dielectric and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:27
L3	0	spring with stack and semicondcutor with dielectric and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:28
L4	11	spring with stack and semiconductor with dielectric and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:29
L5	298	spring with stack and semiconductor and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:30
L6	508	spring with stack$ and semiconductor and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:30
L7	1325	(257/723).CCLS.	USPAT	OR	OFF	2005/03/19 17:30
L8	3	l6 and l7	USPAT	OR	OFF	2005/03/19 17:31
L9	691	edge with contact and semiconductor with stack$	USPAT	OR	OFF	2005/03/19 17:31
L10	40	l7 and l9	USPAT	OR	OFF	2005/03/19 17:41
L11	8	semiconductor with stack and spring with conductor	USPAT	OR	OFF	2005/03/19 17:42
L12	251	semiconductor with stack and spring	USPAT	OR	OFF	2005/03/19 17:42

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	43	spring with curve and stack and dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:26
L2	40	spring with curve and stack and dielectric and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:27
L3	0	spring with stack and semicondcutor with dielectric and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:28
L4	11	spring with stack and semiconductor with dielectric and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:29
L5	298	spring with stack and semiconductor and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:30
L6	508	spring with stack$ and semiconductor and contact	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2005/03/19 17:30